



## LM158-LM258-LM358

### Low power dual operational amplifiers

#### Features

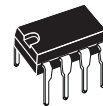
- Internally frequency compensated
- Large DC voltage gain: 100 dB
- Wide bandwidth (unity gain): 1.1 MHz (temperature compensated)
- Very low supply current per operator essentially independent of supply voltage
- Low input bias current: 20 nA (temperature compensated)
- Low input offset voltage: 2 mV
- Low input offset current: 2 nA
- Input common-mode voltage range includes ground
- Differential input voltage range equal to the power supply voltage
- Large output voltage swing 0 V to ( $V_{CC} - 1.5$  V)

#### Description

These circuits consist of two independent, high-gain, internally frequency-compensated op-amps which are designed specifically to operate from a single power supply over a wide range of voltages. The low power supply drain is independent of the magnitude of the power supply voltage.

Application areas include transducer amplifiers, DC gain blocks and all the conventional op-amp circuits which now can be more easily implemented in single power supply systems. For example, these circuits can be directly supplied with the standard +5 V which is used in logic systems and will easily provide the required interface electronics without requiring any additional power supply.

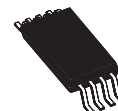
In linear mode, the input common-mode voltage range includes ground and the output voltage can also swing to ground, even though operated from only a single power supply voltage.



**N**  
**DIP-8**  
(Plastic package)

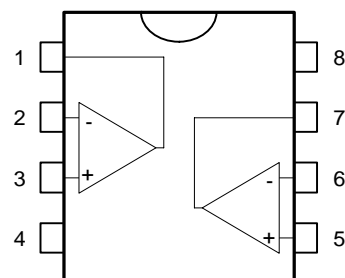


**D & S**  
**SO-8 & miniSO-8**  
(Plastic micropackage)



**P**  
**TSSOP8**  
(Thin shrink small outline package)

#### Pin connections (Top view)



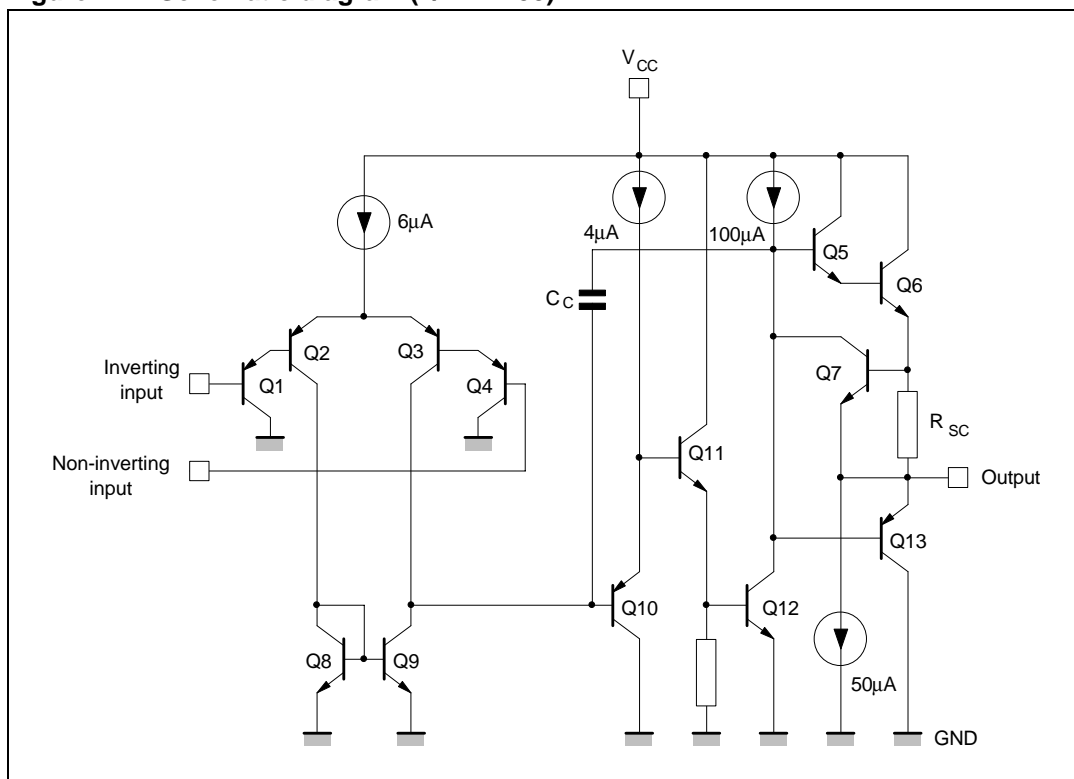
- 1 - Output 1
- 2 - Inverting input
- 3 - Non-inverting input
- 4 -  $V_{CC-}$
- 5 - Non-inverting input 2
- 6 - Inverting input 2
- 7 - Output 2
- 8 -  $V_{CC+}$

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## 1 Schematic diagram

**Figure 1. Schematic diagram (1/2 LM158)**



## 2 Absolute maximum ratings

**Table 1. Absolute maximum ratings**

Symbol	Parameter	LM158,A	LM258,A	LM358,A	Unit
$V_{CC}$	Supply voltage	+/-16 or 32			V
$V_i$	Input voltage	32			V
$V_{id}$	Differential input voltage	32			V
$P_{tot}$	Power dissipation <sup>(1)</sup>	500			mW
	Output short-circuit duation <sup>(2)</sup>	Infinite			
$I_{in}$	Input current <sup>(3)</sup>	50			mA
$T_{oper}$	Operating free-air temperature range	-55 to +125	-40 to +105	0 to +70	°C
$T_{stg}$	Storage temperature range	-65 to +150			°C
$T_j$	Maximum junction temperature	150			°C
$R_{thja}$	Thermal resistance junction to ambient <sup>(4) (5)</sup> SO-8 MiniSO-8 TSSOP8 DIP-8	125 190 120 85			°C/W
$R_{thjc}$	Thermal resistance junction to case SO-8 MiniSO-8 TSSOP8 DIP-8	40 39 37 41			°C/W
ESD	HBM: human body model <sup>(6)</sup>	300			V
	MM: machine model <sup>(7)</sup>	200			V
	CDM: charged device model <sup>(8)</sup>	1.5			kV

1. Power dissipation must be considered to ensure that the maximum junction temperature ( $T_j$ ) is not exceeded.
2. Short-circuits from the output to  $V_{CC}$  can cause excessive heating if  $V_{CC} > 15$  V. The maximum output current is approximately 40 mA independent of the magnitude of  $V_{CC}$ . Destructive dissipation can result from simultaneous short-circuits on all amplifiers.
3. This input current only exists when the voltage at any of the input leads is driven negative. It is due to the collector-base junction of the input PNP transistor becoming forward biased and thereby acting as input diode clamps. In addition to this diode action, there is also NPN parasitic action on the IC chip. This transistor action can cause the output voltages of the Op-amps to go to the  $V_{CC}$  voltage level (or to ground for a large overdrive) for the time during which an input is driven negative. This is not destructive and normal output is restored for input voltages above -0.3 V.
4. Short-circuits can cause excessive heating and destructive dissipation.
5.  $R_{th}$  are typical values.
6. Human body model: A 100pF capacitor is charged to the specified voltage, then discharged through a 1.5k $\Omega$  resistor between two pins of the device. This is done for all couples of connected pin combinations while the other pins are floating.
7. Machine model: A 200pF capacitor is charged to the specified voltage, then discharged directly between two pins of the device with no external series resistor (internal resistor < 5 $\Omega$ ). This is done for all couples of connected pin combinations while the other pins are floating.
8. Charged device model: all pins and the package are charged together to the specified voltage and then discharged directly to the ground through only one pin. This is done for all pins.

### 3 Operating conditions

**Table 2. Operating conditions**

Symbol	Parameter	Value	Unit
$V_{CC}$	Supply voltage	3 to 32	V
$V_{icm}$	Common mode input voltage range $T_{amb} = +25^{\circ}\text{C}$	$V_{DD} - 0.3$ to $V_{CC} - 1.5$	V
$T_{oper}$	Operating free air temperature range LM158 LM258 LM358 LM258Y-LM358Y	-55 - +125 -40 - +105 0 - +70 -40 - +125	$^{\circ}\text{C}$

## 4 Electrical characteristics

**Table 3. Electrical characteristics for  $V_{CC}^+ = +5V$ ,  $V_{CC}^- = \text{Ground}$ ,  $V_O = 1.4V$ ,  $T_{amb} = +25^\circ C$  (unless otherwise specified)**

Symbol	Parameter	LM158A-LM258A LM358A			LM158-LM258 LM358			Unit
		Min.	Typ.	Max.	Min.	Typ.	Max.	
$V_{io}$	Input offset voltage <sup>(1)</sup> $T_{amb} = +25^\circ C$ LM158, LM258 LM158A		1	3		2	7 5	mV
	$T_{min} \leq T_{amb} \leq T_{max}$ LM158, LM258			4			9 7	
$I_{io}$	Input offset current $T_{amb} = +25^\circ C$ $T_{min} \leq T_{amb} \leq T_{max}$		2	10 30		2	30 40	nA
$I_{ib}$	Input bias current <sup>(2)</sup> $T_{amb} = +25^\circ C$ $T_{min} \leq T_{amb} \leq T_{max}$		20	50 100		20	150 200	nA
$A_{vd}$	Large signal voltage gain $V_{CC} = +15 V$ , $R_L = 2 k\Omega$ , $V_O = 1.4 V$ to $11.4 V$ $T_{amb} = +25^\circ C$ $T_{min} \leq T_{amb} \leq T_{max}$	50 25	100		50 25	100		V/mV
SVR	Supply voltage rejection ratio ( $R_s \leq 10 k\Omega$ ) $V_{CC}^+ = 5 V$ to $30 V$ $T_{amb} = +25^\circ C$ $T_{min} \leq T_{amb} \leq T_{max}$	65 65	100		65 65	100		dB
$I_{CC}$	Supply current, all amp, no load $T_{min} \leq T_{amb} \leq T_{max}$ $V_{CC} = +5 V$ $T_{min} \leq T_{amb} \leq T_{max}$ $V_{CC} = +30 V$		0.7	1.2 2		0.7	1.2 2	mA
$V_{icm}$	Input common mode voltage range $V_{CC} = +30 V$ <sup>(3)</sup> $T_{amb} = +25^\circ C$ $T_{min} \leq T_{amb} \leq T_{max}$	0 0		$V_{CC}^+ - 1.5$ $V_{CC}^+ - 2$	0 0		$V_{CC}^+ - 1.5$ $V_{CC}^+ - 2$	V
CMR	Common mode rejection ratio ( $R_s \leq 10 k\Omega$ ) $T_{amb} = +25^\circ C$ $T_{min} \leq T_{amb} \leq T_{max}$	70 60	85		70 60	85		dB
$I_{source}$	Output current source $V_{CC} = +15 V$ , $V_O = +2 V$ , $V_{id} = +1 V$	20	40	60	20	40	60	mA
$I_{sink}$	Output sink current ( $V_{id} = -1V$ ) $V_{CC} = +15V$ , $V_O = +2V$ $V_{CC} = +15V$ , $V_O = +0.2V$	10	20		10	20		mA
		12	50		12	50		$\mu A$

**Table 3. Electrical characteristics for  $V_{CC}^+ = +5V$ ,  $V_{CC}^- = \text{Ground}$ ,  $V_O = 1.4V$ ,  $T_{amb} = +25^\circ C$  (unless otherwise specified)**

Symbol	Parameter	LM158A-LM258A LM358A			LM158-LM258 LM358			Unit
		Min.	Typ.	Max.	Min.	Typ.	Max.	
$V_{OPP}$	Output voltage swing ( $R_L = 2\text{ k}\Omega$ ) $T_{amb} = +25^\circ C$ $T_{min} \leq T_{amb} \leq T_{max}$	0 0		$V_{CC}^+ - 1.5$ $V_{CC}^+ - 2$	0 0		$V_{CC}^+ - 1.5$ $V_{CC}^+ - 2$	
$V_{OH}$	High level output voltage ( $V_{CC}^+ = 30\text{ V}$ ) $T_{amb} = +25^\circ C$ , $R_L = 2\text{ k}\Omega$ $T_{min} \leq T_{amb} \leq T_{max}$ $T_{amb} = +25^\circ C$ , $R_L = 10\text{ k}\Omega$ $T_{min} \leq T_{amb} \leq T_{max}$	26 26 27 27	27 28		26 26 27 27	27 28		V
$V_{OL}$	Low level output voltage ( $R_L = 10\text{ k}\Omega$ ) $T_{amb} = +25^\circ C$ $T_{min} \leq T_{amb} \leq T_{max}$		5	20 20		5	20 20	mV
SR	Slew rate $V_{CC} = 15V$ , $V_i = 0.5$ to $3V$ , $R_L = 2\text{ k}\Omega$ $C_L = 100\text{ pF}$ , unity Gain	0.3	0.6		0.3	0.6		V/ $\mu s$
GBP	Gain bandwidth product $V_{CC} = 30\text{ V}$ , $f = 100\text{ kHz}$ , $V_{in} = 10\text{ mV}$ , $R_L = 2\text{ k}\Omega$ , $C_L = 100\text{ pF}$	0.7	1.1		0.7	1.1		MHz
THD	Total harmonic distortion $f = 1\text{ kHz}$ , $A_v = 20\text{ dB}$ , $R_L = 2\text{ k}\Omega$ , $V_O = 2\text{ V}_{pp}$ , $C_L = 100\text{ pF}$ , $V_O = 2\text{ V}_{pp}$		0.02			0.02		%
$e_n$	Equivalent input noise voltage $f = 1\text{ kHz}$ , $R_s = 100\text{ }\Omega$ , $V_{CC} = 30\text{ V}$		55			55		$\frac{nV}{\sqrt{Hz}}$
$DV_{io}$	Input offset voltage drift		7	15		7	30	$\mu V/^\circ C$
$DI_{io}$	Input offset current drift		10	200		10	300	pA/ $^\circ C$
$V_{O1}/V_{O2}$	Channel separation <sup>(4)</sup> $1\text{ kHz} \leq f \leq 20\text{ kHz}$		120			120		dB

- $V_O = 1.4\text{ V}$ ,  $R_s = 0\text{ }\Omega$ ,  $5\text{ V} < V_{CC}^+ < 30\text{ V}$ ,  $0 < V_{ic} < V_{CC}^+ - 1.5\text{ V}$
- The direction of the input current is out of the IC. This current is essentially constant, independent of the state of the output so there is no change in the load on the input lines.
- The input common-mode voltage of either input signal voltage should not be allowed to go negative by more than  $0.3\text{ V}$ . The upper end of the common-mode voltage range is  $V_{CC}^+ - 1.5\text{ V}$ , but either or both inputs can go to  $+32\text{ V}$  without damage.
- Due to the proximity of external components, ensure that stray capacitance between these external parts does not cause coupling. Typically, this can be detected because this type of capacitance increases at higher frequencies.

Figure 2. Open loop frequency response

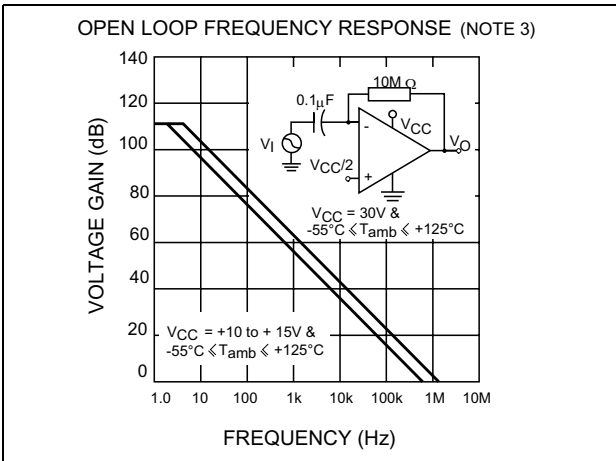


Figure 3. Large signal frequency response

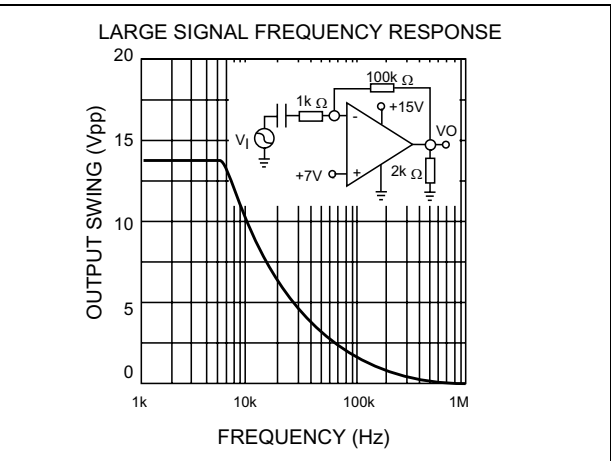


Figure 4. Voltage follower pulse response

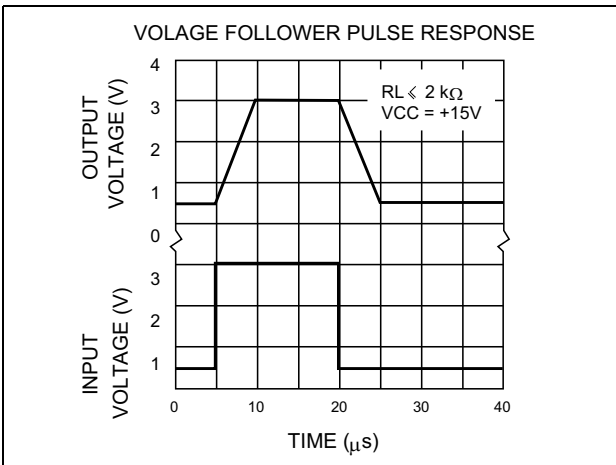


Figure 5. Voltage follower pulse response

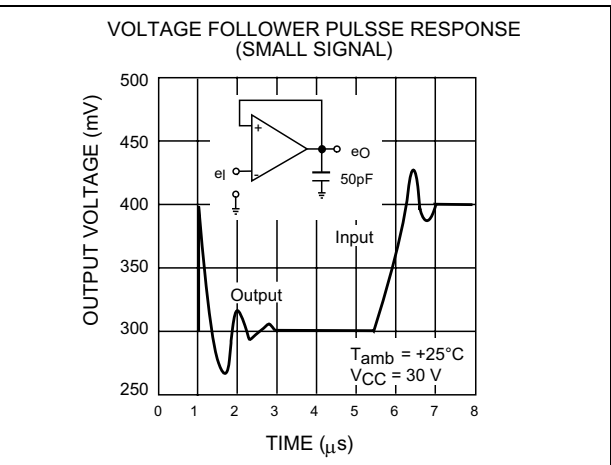


Figure 6. Input current

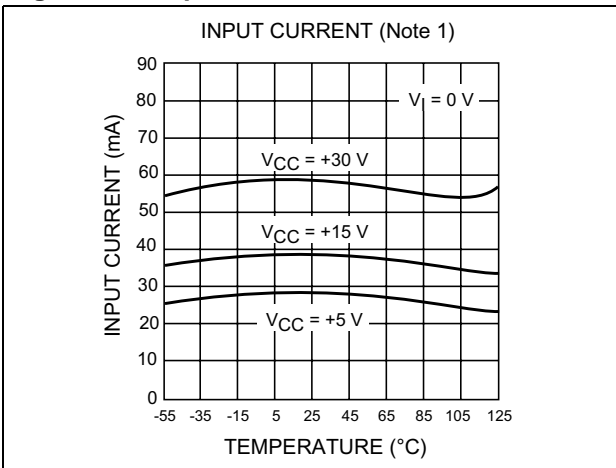


Figure 7. Output characteristics

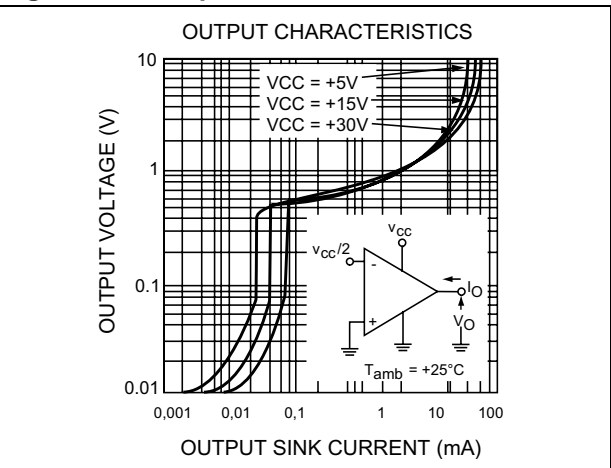


Figure 8. Output characteristics

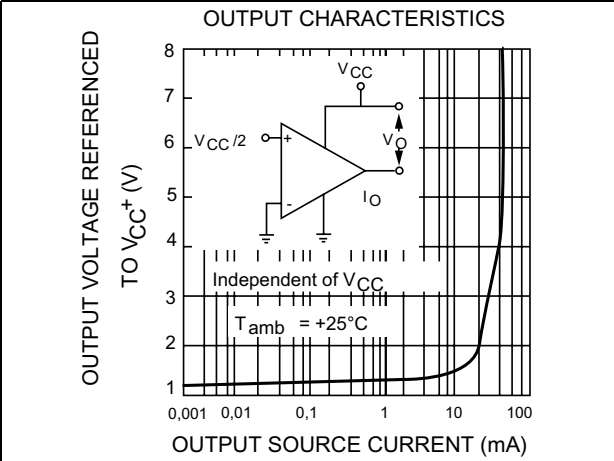


Figure 9. Current limiting

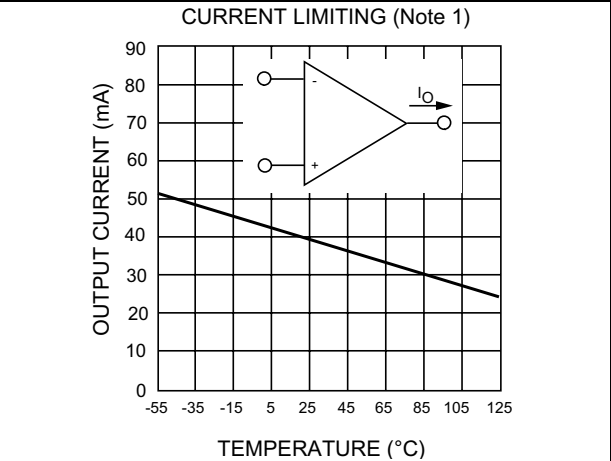


Figure 10. Input voltage range

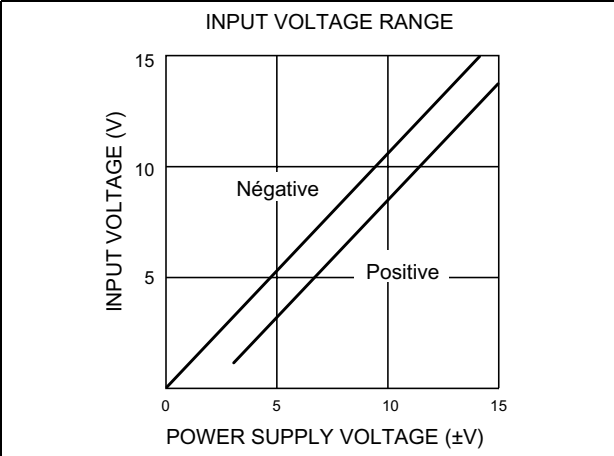


Figure 11. Positive supply voltage

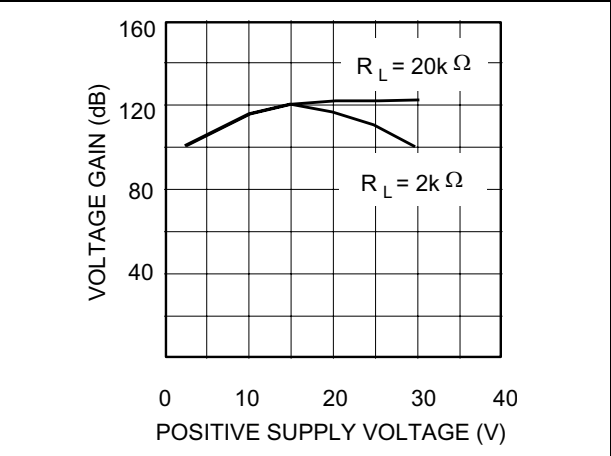


Figure 12. Input voltage range

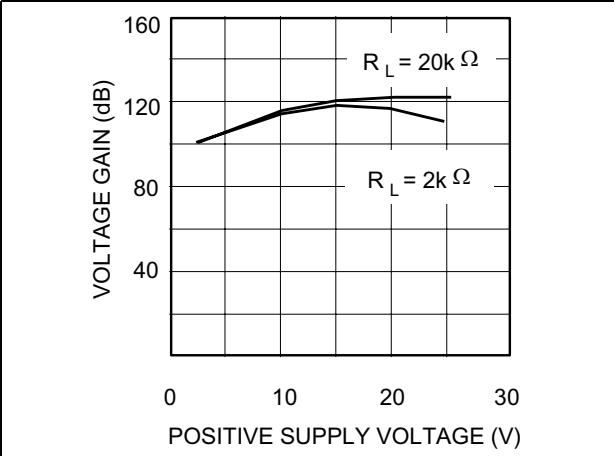


Figure 13. Supply current

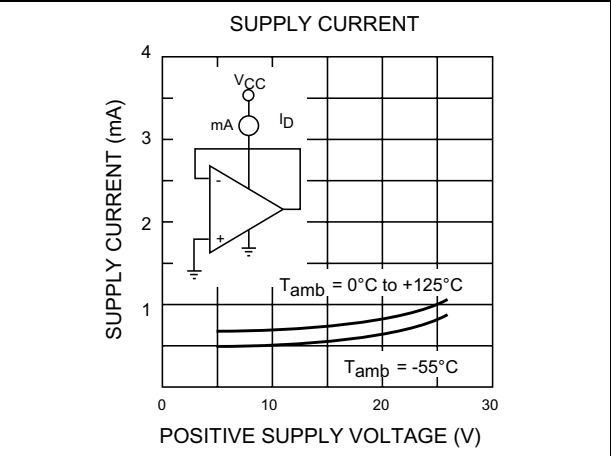


Figure 14. Input current

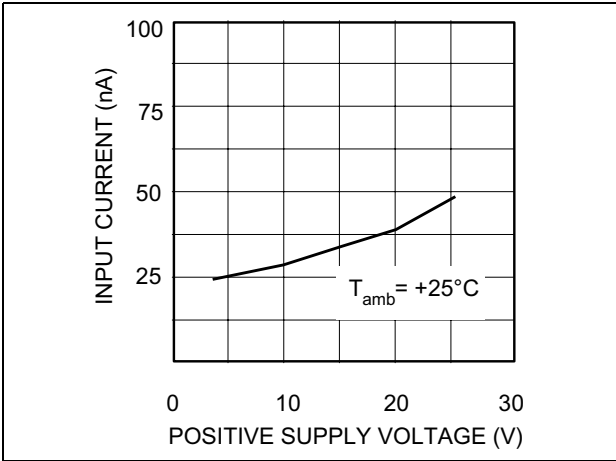


Figure 15. Gain bandwidth product

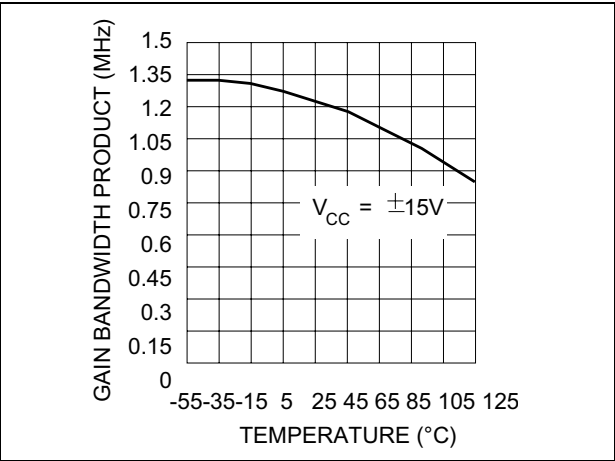


Figure 16. Power supply rejection ratio

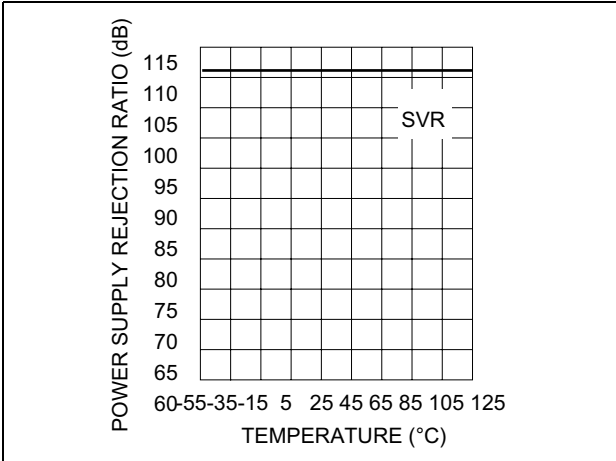


Figure 17. Common mode rejection ratio

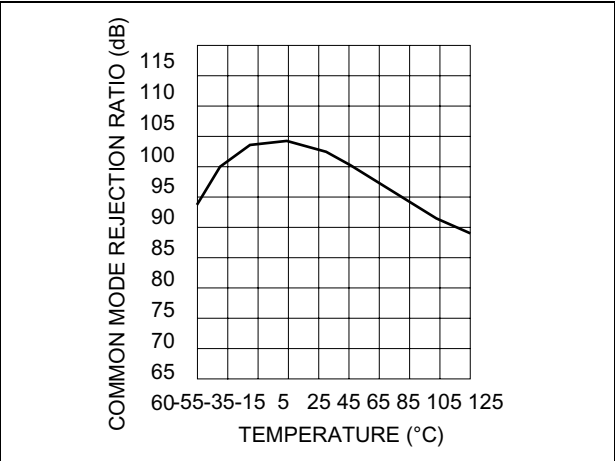
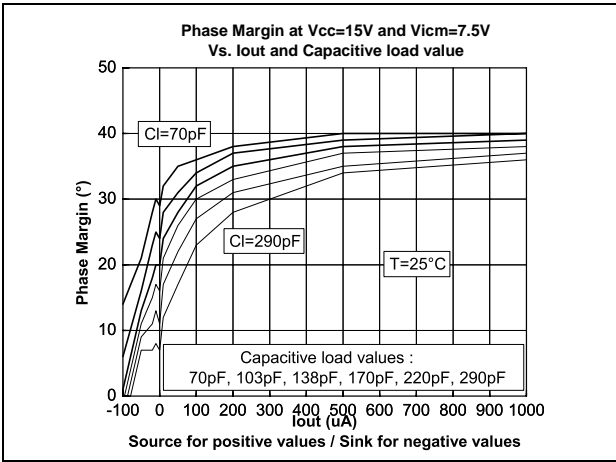


Figure 18. Phase margin vs capacitive load



## 5 Typical applications

Single supply voltage  $V_{CC} = +5V_{dc}$ .

Figure 19. AC coupled inverting amplifier

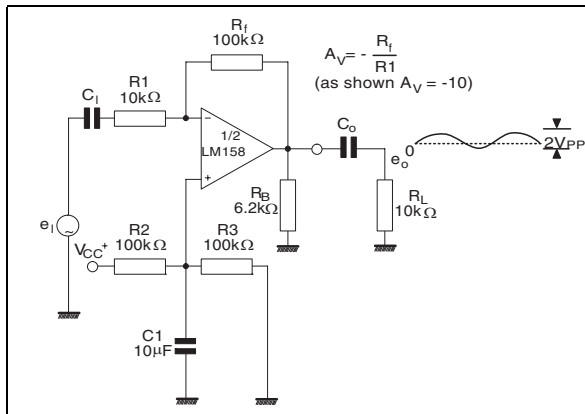


Figure 20. Non-inverting DC amplifier

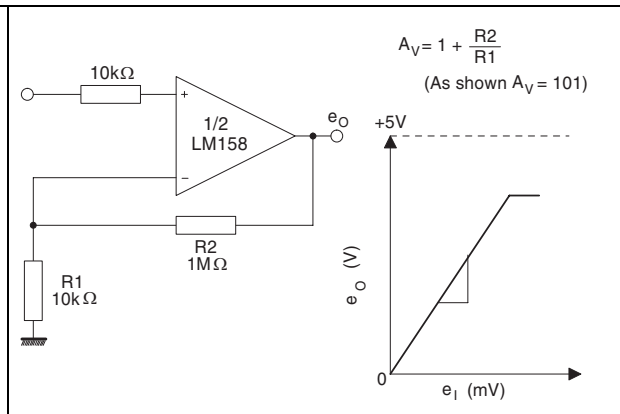


Figure 21. AC coupled non-inverting amplifier

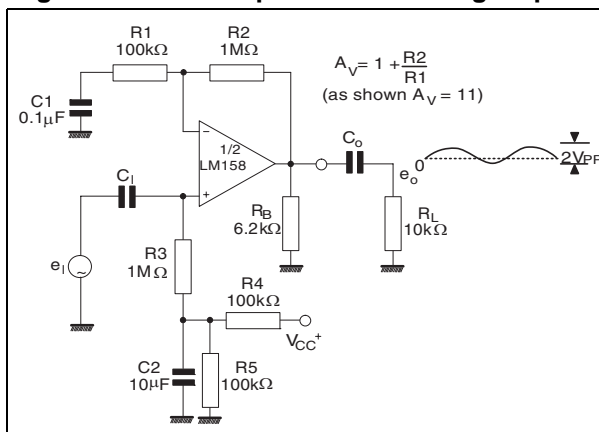


Figure 22. DC summing amplifier

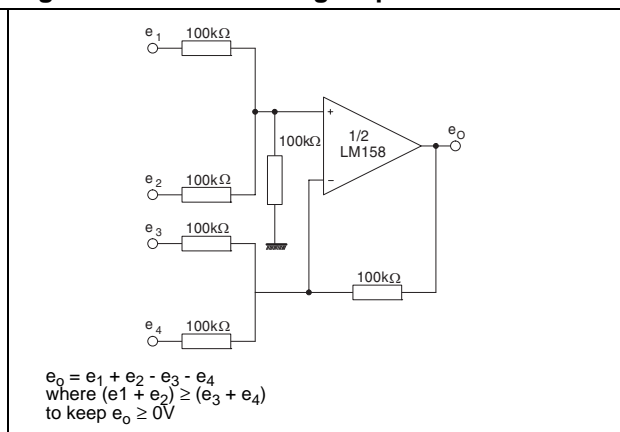


Figure 23. High input Z, DC differential amplifier

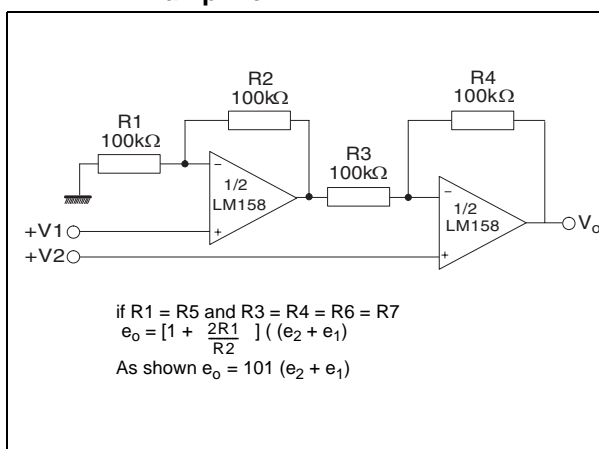
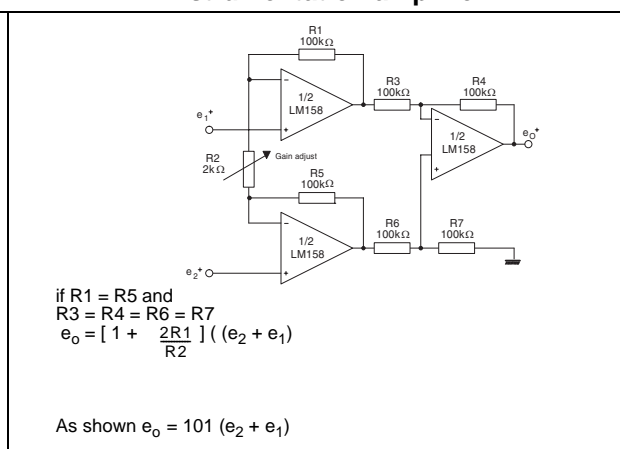
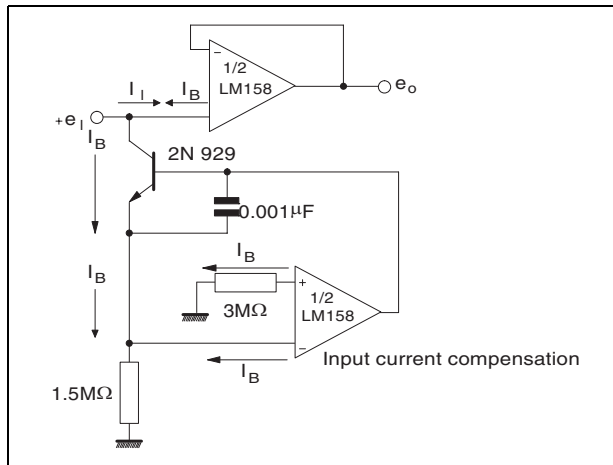


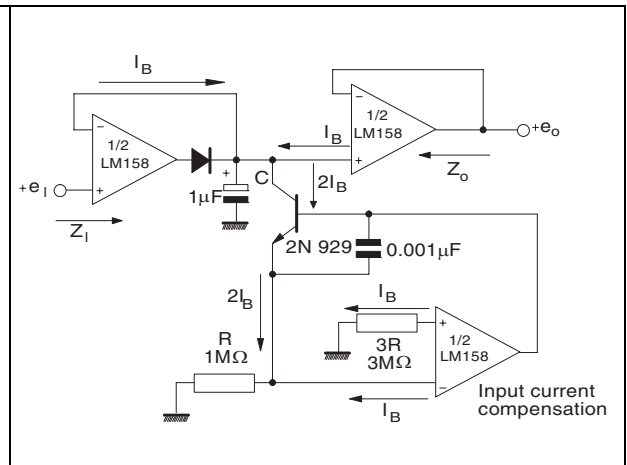
Figure 24. High input Z adjustable gain DC instrumentation amplifier



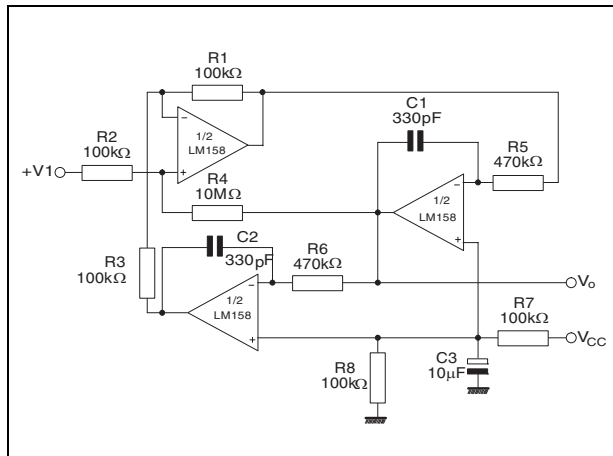
**Figure 25. Using symmetrical amplifiers to reduce input current**



**Figure 26. Low drift peak detector**



**Figure 27. Active band-pass filter**



## 6 Package information

In order to meet environmental requirements, STMicroelectronics offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an STMicroelectronics trademark. ECOPACK specifications are available at: [www.st.com](http://www.st.com).

## 6.1 DIP8 package

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			5.33			0.210
A1	0.38			0.015		
A2	2.92	3.30	4.95	0.115	0.130	0.195
b	0.36	0.46	0.56	0.014	0.018	0.022
b2	1.14	1.52	1.78	0.045	0.060	0.070
c	0.20	0.25	0.36	0.008	0.010	0.014
D	9.02	9.27	10.16	0.355	0.365	0.400
E	7.62	7.87	8.26	0.300	0.310	0.325
E1	6.10	6.35	7.11	0.240	0.250	0.280
e		2.54			0.100	
eA		7.62			0.300	
eB			10.92			0.430
L	2.92	3.30	3.81	0.115	0.130	0.150

The figure contains three mechanical drawings of the DIP8 package:

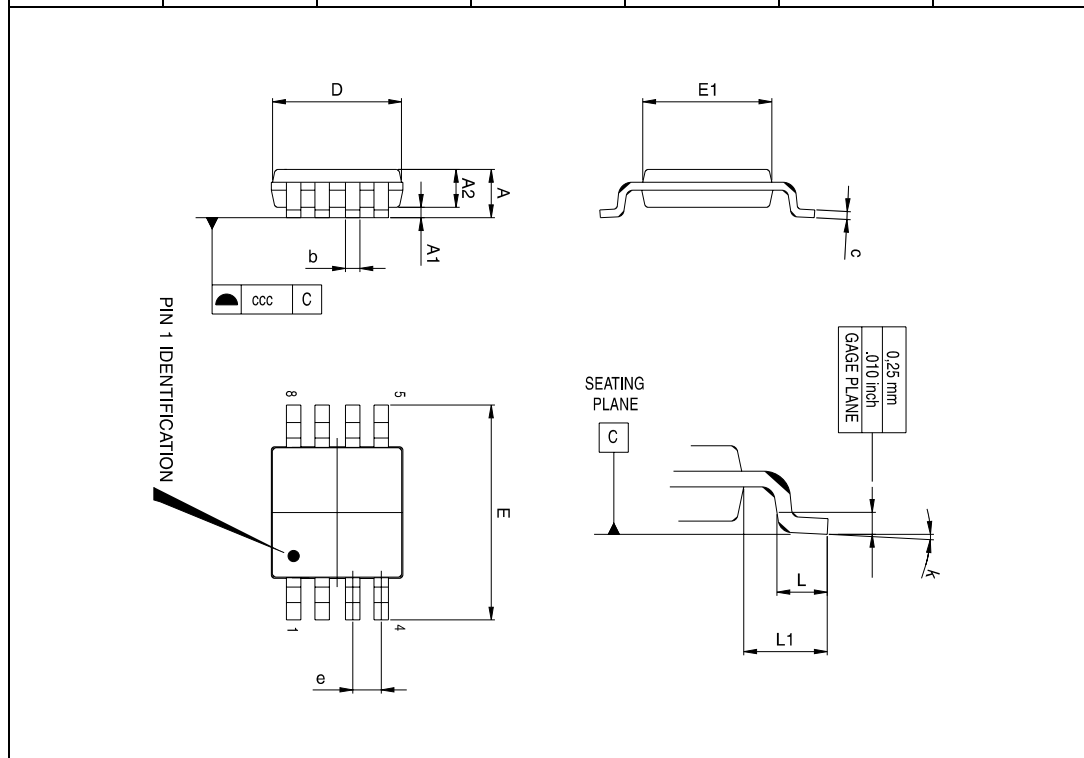
- Top View:** Shows the package footprint with dimensions D (width), E1 (height), and pin locations. Pin numbers 1, 4, 5, and 8 are indicated.
- Side View:** Shows the package height with dimensions A, A1, A2, L, b, b2, c, e, eA, eB, and E.
- Detail View:** A magnified view of the lead profile showing the gauge plane at 0.38 mm and the lead height H.

## 6.2 SO-8 package

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.75			0.069
A1	0.10		0.25	0.004		0.010
A2	1.25			0.049		
b	0.28		0.48	0.011		0.019
c	0.17		0.23	0.007		0.010
D	4.80	4.90	5.00	0.189	0.193	0.197
E	5.80	6.00	6.20	0.228	0.236	0.244
E1	3.80	3.90	4.00	0.150	0.154	0.157
e		1.27			0.050	
h	0.25		0.50	0.010		0.020
L	0.40		1.27	0.016		0.050
k	1°		8°	1°		8°
ccc			0.10			0.004

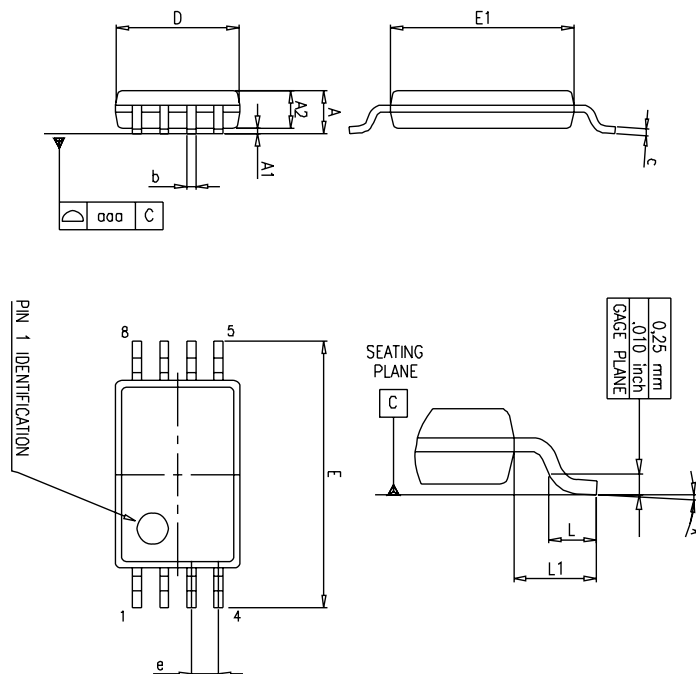
### 6.3 MiniSO-8 package

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.1			0.043
A1	0.05	0.10	0.15	0.002	0.004	0.006
A2	0.78	0.86	0.94	0.031	0.034	0.037
b	0.25	0.33	0.40	0.010	0.013	0.016
c	0.13	0.18	0.23	0.005	0.007	0.009
D	2.90	3.00	3.10	0.114	0.118	0.122
E	4.75	4.90	5.05	0.187	0.193	0.199
E1	2.90	3.00	3.10	0.114	0.118	0.122
e		0.65			0.026	
K	0°		6°	0°		6°
L	0.40	0.55	0.70	0.016	0.022	0.028
L1			0.10			0.004



## 6.4 TSSOP8 package

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.2			0.047
A1	0.05		0.15	0.002		0.006
A2	0.80	1.00	1.05	0.031	0.039	0.041
b	0.19		0.30	0.007		0.012
c	0.09		0.20	0.004		0.008
D	2.90	3.00	3.10	0.114	0.118	0.122
E	6.20	6.40	6.60	0.244	0.252	0.260
E1	4.30	4.40	4.50	0.169	0.173	0.177
e		0.65			0.0256	
k	0°		8°	0°		8°
L	0.45	0.60	0.75	0.018	0.024	0.030
L1		1			0.039	
aaa		0.1			0.004	



## 7 Ordering information

Part number	Temperature range	Package	Packaging	Marking
LM158N	-55°C, +125°C	DIP-8	Tube	LM158N
LM158D LM158DT		SO-8	Tube or tape & reel	158
LM158YD LM158YDT <sup>(1)</sup>		SO-8 Automotive grade		158Y
LM258AN		-40°C, +105°C	DIP-8	Tube
LM258AD LM258ADT	SO-8		Tube or tape & reel	258A
LM258AYD LM258AYDT <sup>(1)</sup>	SO-8 Automotive grade			258AY
LM258PT	TSSOP-8 (Thin shrink outline package)		Tape & reel	258
LM258APT				258A
LM258YPT <sup>(1)</sup>	TSSOP-8 Automotive grade			258Y
LM258AYPT	258AY			
LM258AST	miniSO-8		Tape & reel	K408
LM258N	DIP-8		Tube	LM258N
LM258D LM258DT	SO-8		Tube or tape & reel	258
LM258YD LM258YDT <sup>(1)</sup>	SO-8 Automotive grade			258Y
LM358N	0°C, +70°C		DIP-8	Tube
LM358AN				LM358AN
LM358D LM358DT		SO-8	Tube or tape & reel	358
LM358YD LM358YDT <sup>(1)</sup>		SO-8 Automotive grade		358Y
LM358AD LM358ADT		SO-8		358A
LM358PT		TSSOP-8 (Thin shrink outline package)	Tape & reel	358
LM358APT				358A
LM358YPT <sup>(1)</sup>		TSSOP-8 Automotive grade		358Y
LM358AYPT <sup>(1)</sup>		358AY		
LM358ST		miniSO-8	Tape & reel	K405
LM358AST				K404

1. Qualified and characterized according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 & Q 002 or equivalent.

## 8 Revision history

Date	Revision	Changes
1-Jul- 2003	1	First release.
2-Jan-2005	2	$R_{thja}$ and $T_j$ parameters added in AMR <a href="#">Table 1 on page 4</a> .
1-Jul-2005	3	ESD protection inserted in <a href="#">Table 1 on page 4</a> .
5-Oct-2006	4	Added <a href="#">Figure 18: Phase margin vs capacitive load</a> .
30-Nov-2006	5	Added missing ordering information.
25-Apr-2007	6	Removed LM158A, LM258A and LM358A from document title. Corrected error in miniSO8 package data. L1 is 0.004 inch. Added automotive grade order codes in <a href="#">Section 7 on page 18</a> .

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